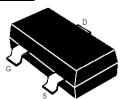
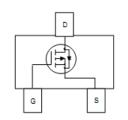
**BML6402** 







#### **Features**

- Advanced trench process technology
- High Density Cell Design For Ultra Low On-Resistance

## **MAXIMUM RANTINGS**

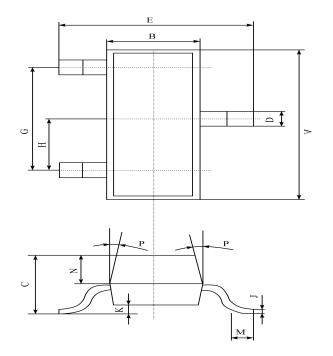
Characteristic	Symbol	Max	Unit	
Drain-Source Voltage	$BV_{DSS}$	-20	V	
Gate- Source Voltage	$V_{ m GS}$	<u>+</u> 12	V	
Drain Current (continuous)	$I_D$	-3.7	A	
Drain Current (pulsed)	$I_{DM}$	-15	A	
Total Device Dissipation T <sub>A</sub> =25°C	PD	1100	mW	
Junction	T <sub>J</sub>	150	$^{\circ}\!\mathbb{C}$	
Storage Temperature	$T_{ m stg}$	-55to+150	$^{\circ}\!\mathbb{C}$	

# **Electrical Characteristics**

Characteristic	Symbol	Min	Тур	Max	Unit
Drain-Source Breakdown Voltage (I <sub>D</sub> = -250uA,V <sub>GS</sub> =0V)	BV <sub>DSS</sub>	-20			V
Gate Threshold Voltage (I <sub>D</sub> = -250uA, V <sub>GS</sub> = V <sub>DS</sub> )	V <sub>GS(th)</sub>	-0.4		-1.2	V
Diode Forward Voltage Drop (I <sub>s</sub> = -1 A,V <sub>GS</sub> =0V)	V <sub>SD</sub>	_	_	-1.2	V
Zero Gate Voltage Drain Current (V <sub>GS</sub> =0V, V <sub>DS</sub> = -20V) (V <sub>GS</sub> =0V, V <sub>DS</sub> = -20V, T <sub>A</sub> =70°C)	IDSS			-1 -25	uA
Gate Body Leakage (V <sub>GS</sub> =±12V, V <sub>DS</sub> =0V)	IGSS	_	_	<u>+</u> 100	пA
Static Drain-Source On-State Resistance (I <sub>D</sub> = -3.7A,V <sub>GS</sub> = -4.5V)	R <sub>DS(ON)</sub>		50	65	mΩ
Static Drain-Source On-State Resistance $(I_D=-3.1A, V_{GS}=-2.5V)$	R <sub>DS(ON)</sub>		80	135	m $\Omega$
Input Capacitance (V <sub>GS</sub> =0V, V <sub>DS</sub> = -10V,f=1MHz)	Ciss		600		pF
Output Capacitance (V <sub>GS</sub> =0V, V <sub>DS</sub> = -10V,f=1MHz)	Coss	_	120		pF
Turn-ON Time (V <sub>DS</sub> = -10V, I <sub>D</sub> = -3.7A, R <sub>GEN</sub> =6 $\Omega$ )	t(on)	<u> </u>	8	_	ns
Turn-OFF Time $(V_{DS}=-10V, I_{D}=-3.7A, R_{GEN}=6\Omega)$	t(off)		60	_	ns



### SOT-23 PACKAGE OUTLINE Plastic surface mounted package



	SOT-23		
301-23			
Α	$2.90 \pm 0.10$		
В	$1.30 \pm 0.10$		
С	$1.00 \pm 0.10$		
D	$0.40 \pm 0.10$		
Е	$2.40\pm0.20$		
G	$1.90 \pm 0.10$		
Н	$0.95 \pm 0.05$		
J	$0.13 \pm 0.05$		
K	0.00-0.10		
M	≥0.2		
Z	$0.60 \pm 0.10$		
P	7 ± 2 °		

(UNIT): mm